

»Features

- 70Watts peak pulse power ($t_p = 8/20\mu s$)
- Protect up to 2-lines
- Solid-state silicon-avalanche technology
- Low clamping voltage
- Low leakage current
- Low capacitance ($C_j=0.28\text{pF}$ typ. I/O to I/O)
- IEC 61000-4-2 $\pm 8\text{kV}$ contact $\pm 15\text{kV}$ air
- IEC 61000-4-4 (EFT) 40A(5/50ns)
- IEC 61000-4-5 (Lightning) 3.5A (8/20 μs)



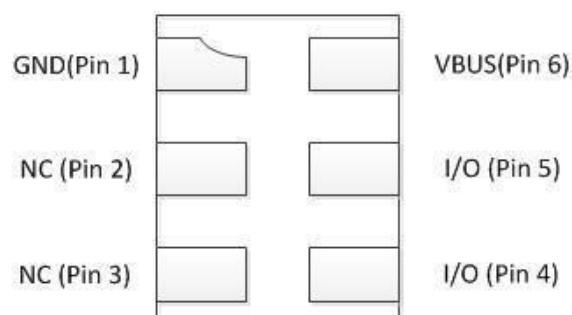
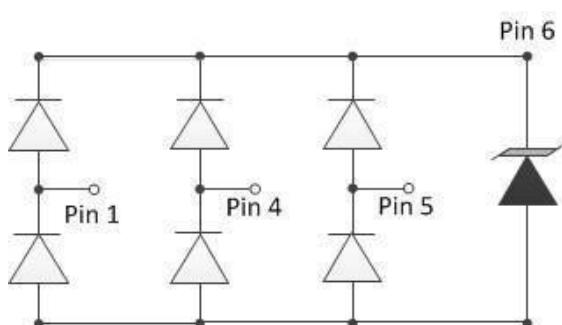
»Applications

- USB 2.0
- MMC Port
- Video Port
- Digital visual interface

»Mechanical Data

- DFN1109-6L package
- Molding compound flammability rating: UL 94V-0
- Packaging: Tape and Reel
- RoHS/WEEE Compliant

»Schematic & PIN Configuration



»Absolute Maximum Rating

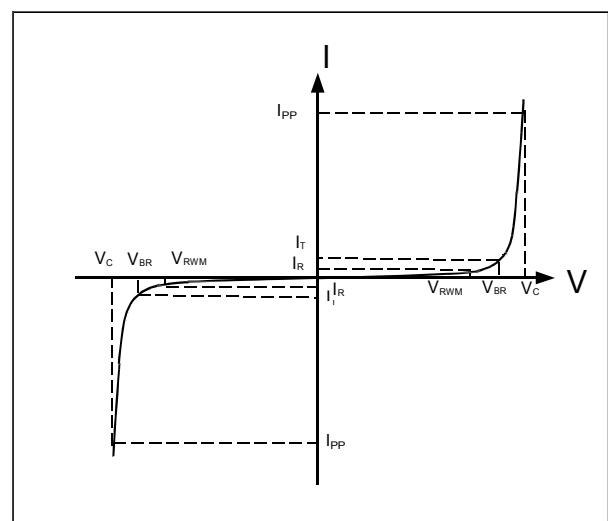
Rating	Symbol	Value	Units
Peak Pulse Power ($t_p = 8/20\mu s$)	P _{PP}	70	Watts
Peak Pulse Current ($t_p = 8/20\mu s$)(note1)	I _{pp}	3.5	A
ESD per IEC 61000-4-2(Air) ESD per IEC 61000-4-2(Contact)	V _{ESD}	15 8	kV
Lead Soldering Temperature	T _L	260(10seconds)	°C
Junction Temperature	T _J	-55 to +125	°C
Storage Temperature	T _{stg}	-55 to +125	°C

»Electrical Characteristics

Parameter	Symbol	Conditions	Min	Typical	Max	Units
Reverse Stand-Off Voltage	V _{RWM}				5.0	V
Reverse Breakdown Voltage	V _{BR}	I _T =1mA	6.0	7.2	9.5	V
Reverse Leakage Current	I _R	V _{RWM} =5V,T=25°C		0.1	0.5	µA
Peak Pulse Current	I _{PP}	tp = 8/20µs			3.5	A
Clamping Voltage	V _C	IPP=3.5A, tp=8/20µs			20	V
Junction Capacitance	C _J	V _R = 0V, f = 1MHz I/O to I/O		0.28	0.4	pF
		V _R = 0V, f = 1MHz I/O to GND		0.28	0.4	pF

»Electrical Parameters (TA = 25°C unless otherwise noted)

Symbol	Parameter
I _{PP}	Maximum Reverse Peak Pulse Current
V _C	Clamping Voltage @ I _{PP}
V _{RWM}	Working Peak Reverse Voltage
I _R	Maximum Reverse Leakage Current @ V _{RWM}
V _{BR}	Breakdown Voltage @ I _T
I _T	Test Current



Note: 8/20µs pulsed waveform.

»TypicalCharacteristics

Fig.1 IEC61000-4-2Waveform

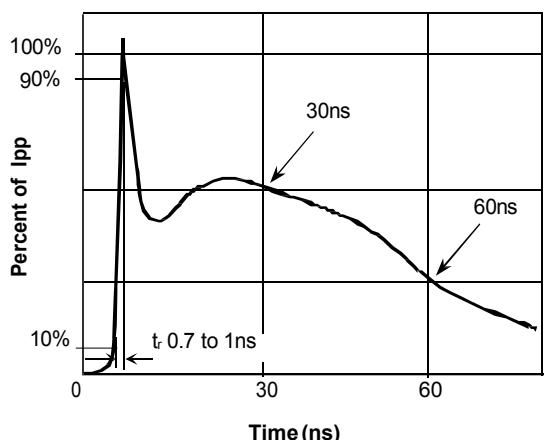


Fig.2 IEC61000-4-2 +8kV ContactESD Clamping Waveform

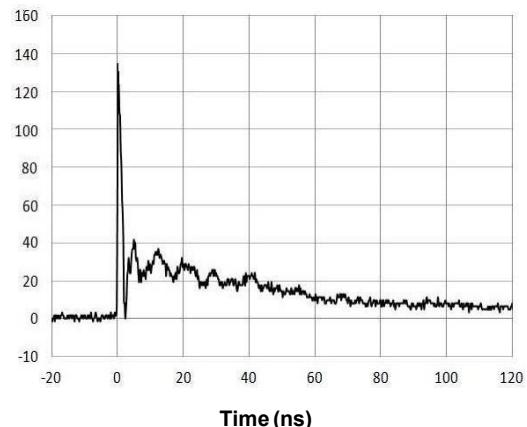


Fig.3 Eye Diagram - perchannel

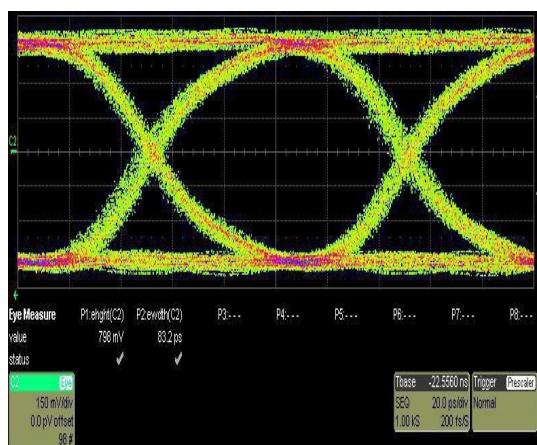
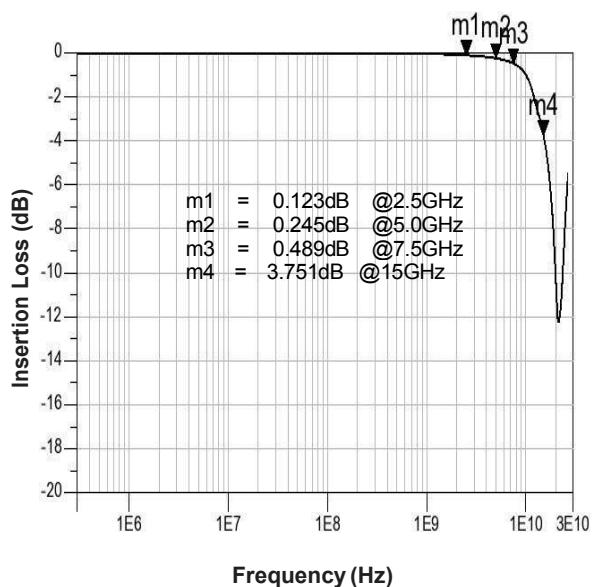
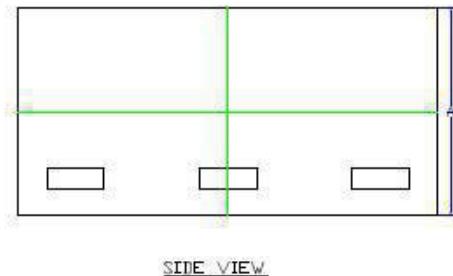
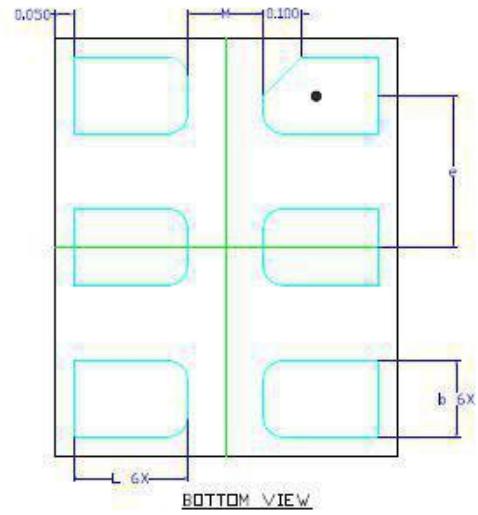
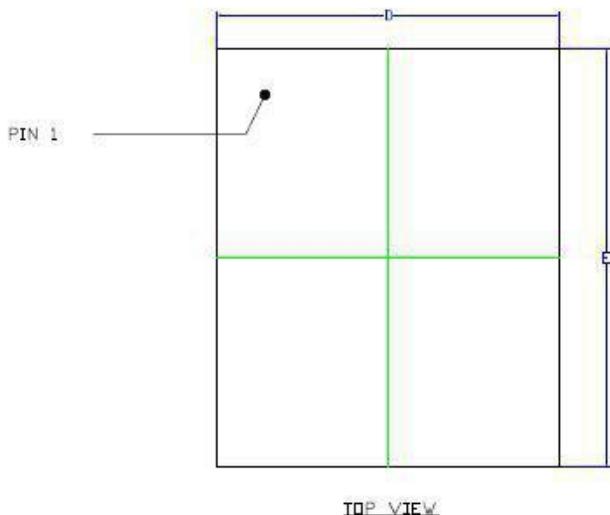


Fig.4 Insertion Loss S21 - I/O to I/O



»Outline Drawing – DFN1109



COMMON DIMENSION (MM)			
PKG	DFN1109		
REF.	MIN.	NOM.	MAX
A	0.40	0.45	0.50
B	0.85	0.90	0.95
E	1.05	1.10	1.15
b	0.15	0.20	0.25
L	0.25	0.30	0.35
M	0.35	0.40	0.45
	0.15	0.20	0.25

»Marking



»Ordering information

Order code	Package	Base qty	Delivery mode
RClamp0502N-N	DFN1109	3000	Tape and reel

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